



2DA12130/Y

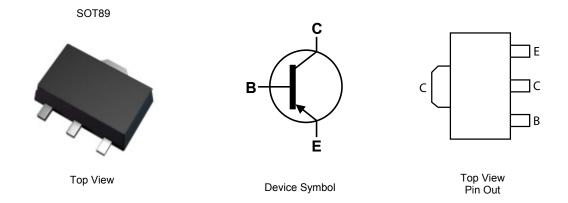
50V PNP POWER SWITCHING TRANSISTOR IN SOT89

Features

- BV_{CEO} > -50V
- I_C = -2A high Continuous Collector Current
- High Gain Holds up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT89
- Case material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.052 grams (Approximate)



Ordering Information (Notes 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
2DA1213O-13	P25X	13	12	2,500
2DA1213Y-13	P25Y	13	12	2,500
2DA1213Y-13R	P25Y	13	12	4,000

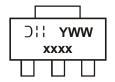
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html

Marking Information



xxxx = Product Type Marking Code: P25X = 2DA1213O P25Y = 2DA1213Y YWW = Date Code Marking Y = Last digit of year (ex: 1 = 2011) WW = Week code 01 - 53



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-50	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	lc	-2	А
Peak Pulse Current	I _{CM}	-2.5	A
Base Current	IB	-500	mA

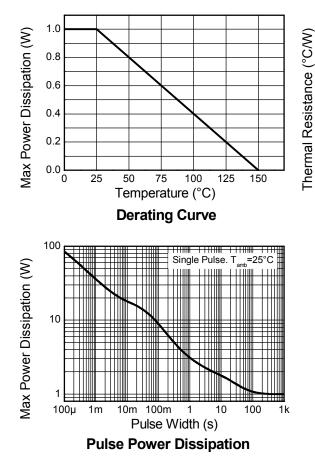
Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

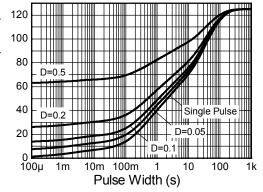
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R _{θJL}	18.3	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Notes: 5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.

6. Thermal resistance from junction to solder-point (on the exposed collector pad).

Thermal Characteristics and Derating Information







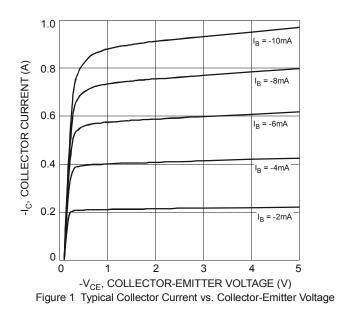


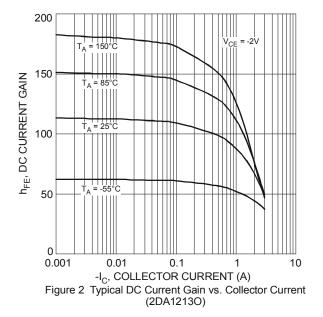
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Мах	Unit	Test Condition	
Collector-Base Breakdown Voltage		BV _{CBO}	-50	_		V	I _C = -100μA	
Collector-Emitter Breakdown Voltage (Note 7)		BV _{CEO}	-50	_		V	$I_{\rm C}$ = -10mA	
Emitter-Base Breakdown Voltage		BV _{EBO}	-6	_		V	I _E = -100μA	
Collector Cut-off Current		I _{CBO}	—	_	-100	nA	$V_{CB} = -50V$	
Emitter Cut-off Current		I _{EBO}	—	_	-100	nA	V _{EB} = -5V	
	2DA1213O	h _{FE}	70		140	_	I _C = -500mA, V _{CE} = -2V	
DC Current Gain (Note 8)	2DA1213Y		120	l —	240		I _C = -500mA, V _{CE} = -2V	
	2DA1213O, 2DA1213Y		20				I _C = -2A, V _{CE} = -2V	
Collector-Emitter Saturation Voltage (Note 7)		V _{CE(sat)}	—	—	-0.5	V	I _C = -1A, I _B = -50mA	
Base-Emitter Turn-On Voltage (Note 7)		V _{BE(sat)}	—	—	-1.2	V	I _C = -1A, I _B = -50mA	
Transition Frequency		f _T	—	160	—	MHz	I _C = -100mA, V _{CE} = -2V, f = 100MHz	
Output Capacitance		C _{obo}	—	17		pF	VCB = -10V, IE = 0, f = 1MHz	
Turn-On Time		t _{on}	_	25		ns	$y_{1} = 0y_{1} + - 40$	
Storage Time		t _(s)	_	130		ns	V _{CE} = -2V, I _C = -1A, I _{B1} = -I _{B2} = -50mA	
Fall Time		t _(f)	_	12	_	ns	1B11B230/11A	

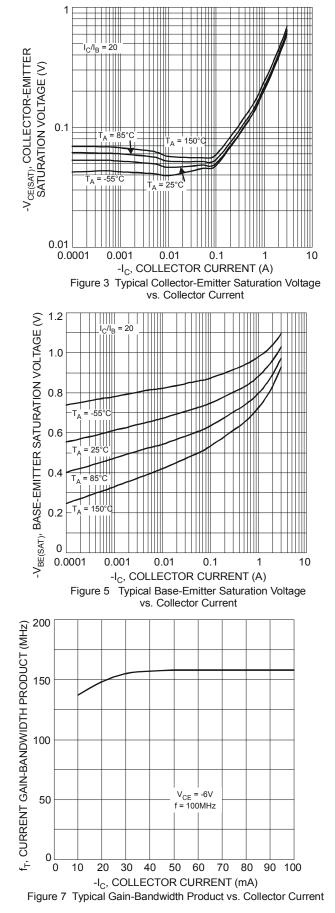
Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

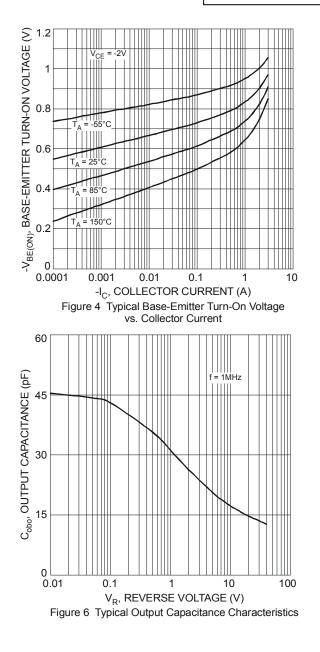
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







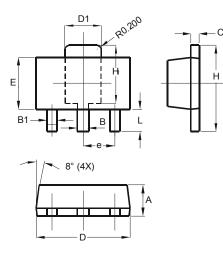






Package Outline Dimensions

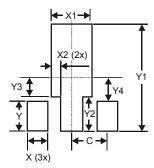
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min Max			
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
ш	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All [All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500



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